

## Features

- Drives up to 360mA from a +12V supply
- 16V<sub>P-P</sub> differential output drive into 25Ω and 20V<sub>P-P</sub> differential output drive into 100Ω
- -85dBc typical driver output distortion at full output at 150kHz
- Low quiescent current of 4mA per amplifier at ½ I<sub>S</sub> current mode
- Disable down to 1.5mA

## Applications

- ADSL CSA line driving
- ADSL full rate CPE line driving
- G.SHDSL, HDSL2 line driver
- Video distribution amplifier
- Video twisted-pair line driver

## Ordering Information

Part No	Package	Tape & Reel	Outline #
EL1511CS	16-Pin SOIC		MDP00XX
EL1511CL	16-Pin LPP		MDP00XX

## General Description

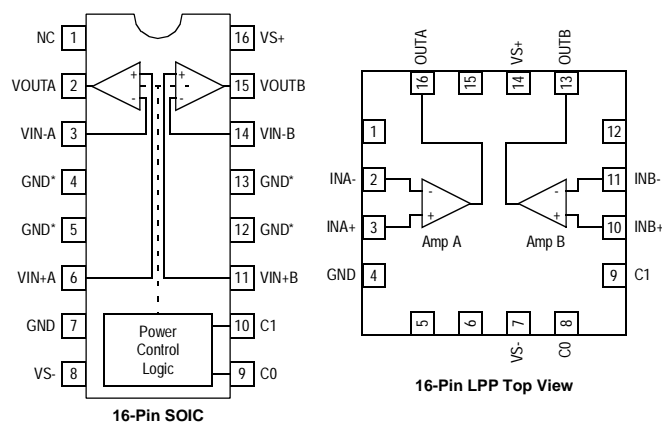
The EL1511C is a dual operational amplifier designed for customer premise line driving in DMT ADSL solutions. This device features a high drive capability of 360mA while consuming only 7.5mA of supply current per amplifier and operating from a single 5 to 12V supply. This driver achieves a typical distortion of less than -85dBc, at 150kHz into a 25Ω load. The EL1511C is available in the thermally-enhanced 16-pin SOIC as well as the 16-pin LPP package. Both are specified for operation over the full -40°C to +85°C temperature range.

The EL1511C has two control pins, C0 and C1 which allow the selection of full I<sub>S</sub> power, ¾ I<sub>S</sub>, ½ I<sub>S</sub>, and power down modes.

The EL1511C is ideal for ADSL, SDSL, and HDSL2 line driving applications for single power supply, high voltage swing, and low power.

The EL1511C maintains excellent distortion and load driving capabilities even in the lowest power settings.

## Connection Diagram



\* These GND pins are heat spreaders

# EL1511C

## Medium Power Differential Line Driver

### Absolute Maximum Ratings $(T_A = 25^\circ\text{C})$

Values beyond absolute maximum ratings can cause the device to be prematurely damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

$V_{S+}$ to $V_{S-}$ Supply Voltage	14.6V
$V_{S+}$ Voltage to Ground	-0.3V to +14.6V
$V_{S-}$ Voltage to Ground	-14.6V to 0.3V
Input $C_0/C_1$ to Ground	7V
$V_{IN+}$ Voltage	$V_{S-}$ to $V_{S+}$

Current into any Input	8mA
Continuous Output Current	75mA
Operating Temperature Range	$-40^\circ\text{C}$ to $+85^\circ\text{C}$
Storage Temperature Range	$-60^\circ\text{C}$ to $+150^\circ\text{C}$
Operating Junction Temperature	$-40^\circ\text{C}$ to $+150^\circ\text{C}$
Power Dissipation	See Curves
ESD Voltage	2kV

#### Important Note:

All parameters having Min/Max specifications are guaranteed. Typ values are for information purposes only. Unless otherwise noted, all tests are at the specified temperature and are pulsed tests, therefore:  $T_J = T_C = T_A$

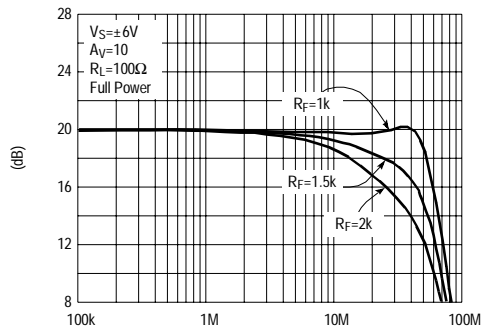
### Electrical Characteristics

$V_S = +12\text{V}$ ,  $R_F = 1.5\text{k}\Omega$ ,  $R_L = 75\Omega$  to mid supply,  $T_A = 25^\circ\text{C}$  unless otherwise specified.

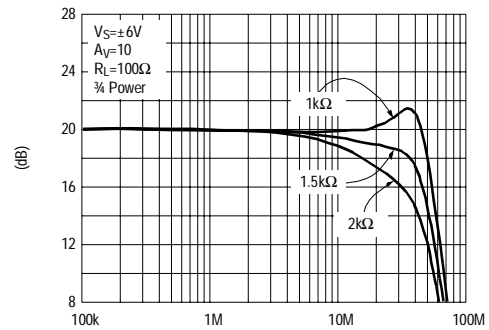
Parameter	Description	Conditions	Min	Typ	Max	Unit
<b>AC Performance</b>						
BW	-3dB Bandwidth	$A_V = +4$		70		MHz
HD	Total Harmonic Distortion	$f = 150\text{kHz}$ , $V_O = 16\text{V}_{P-P}$ , $R_L = 25\Omega$		-85		dBc
dG	Differential Gain	$A_V = +2$ , $R_L = 37.5\Omega$		0.17		%
d $\theta$	Differential Phase	$A_V = +2$ , $R_L = 37.5\Omega$		0.1		°
SR	Slewrate	$V_{OUT}$ from -4.5V to +4.5V		500		V/ $\mu\text{S}$
<b>DC Performance</b>						
$V_{OS}$	Offset Voltage		-20		20	mV
$\Delta V_{OS}$	$V_{OS}$ Mismatch		-10		10	mV
$R_{OL}$	Transimpedance	$V_{OUT}$ from -4.5V to +4.5V		1.4		M $\Omega$
<b>Input Characteristics</b>						
$I_{B+}$	Non-Inverting Input Bias Current		-3		3	$\mu\text{A}$
$I_{B-}$	Inverting Input Bias Current		-30		30	$\mu\text{A}$
$\Delta I_{B-}$	$I_{B-}$ Mismatch		-40		40	$\mu\text{A}$
$e_N$	Input Noise Voltage			2.8		nV/ $\sqrt{\text{Hz}}$
$i_N$	-Input Noise Current			19		pA/ $\sqrt{\text{Hz}}$
<b>Output Characteristics</b>						
$V_{OUT}$	Loaded Output Swing (single ended)	$R_L = 100\Omega$ to GND		11		V
		$R_L = 25\Omega$ to GND		9.4		V
$I_{OUT}$	Output Current	$R_L = 0\Omega$		1		A
<b>Supply</b>						
$V_S$	Supply Voltage	Single Supply	5		12	V
$I_{S+}(\text{Full Power})$	Positive Supply Current per Amplifier	All Outputs at 0V, $C_0 = C_1 = 0\text{V}$		7	8	mA
$I_{S-}(\text{Full Power})$	Negative Supply Current per Amplifier	All Outputs at 0V, $C_0 = C_1 = 0\text{V}$		-6.4	-7.1	mA
$I_{S+}(\text{Low Power})$	Positive Supply Current per Amplifier	All Outputs at 0V, $C_0 = 5\text{V}$ , $C_1 = 0\text{V}$		5.3	6	mA
$I_{S-}(\text{Low Power})$	Negative Supply Current per Amplifier	All Outputs at 0V, $C_0 = 5\text{V}$ , $C_1 = 0\text{V}$		-4.7	-5.3	mA
$I_{S+}(\text{Terminate})$	Positive Supply Current per Amplifier	All Outputs at 0V, $C_0 = 0\text{V}$ , $C_1 = 5\text{V}$		3.3	3.8	mA
$I_{S-}(\text{Terminate})$	Negative Supply Current per Amplifier	All Outputs at 0V, $C_0 = 0\text{V}$ , $C_1 = 5\text{V}$		-2.7	-3.1	mA
$I_{S+}(\text{Power Down})$	Positive Supply Current per Amplifier	All Outputs at 0V, $C_0 = C_1 = 5\text{V}$		0.6	2	mA
$I_{S-}(\text{Power Down})$	Negative Supply Current per Amplifier	All Outputs at 0V, $C_0 = C_1 = 5\text{V}$		0	1.5	mA
$I_{GND}$	GND Supply Current per Amplifier	All Outputs at 0V		0.6	2	mA

### Typical Performance Curves

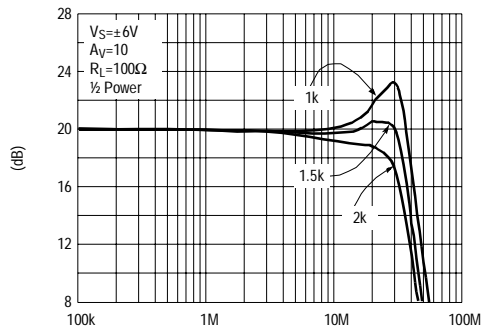
Differential Frequency Response vs  $R_F$



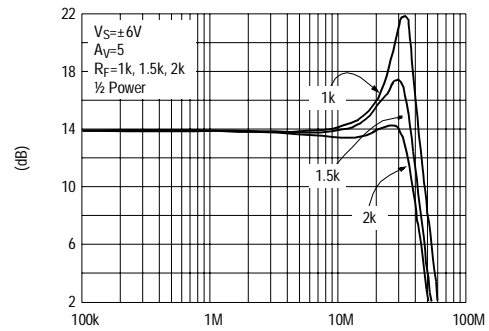
Differential Frequency vs  $R_F$



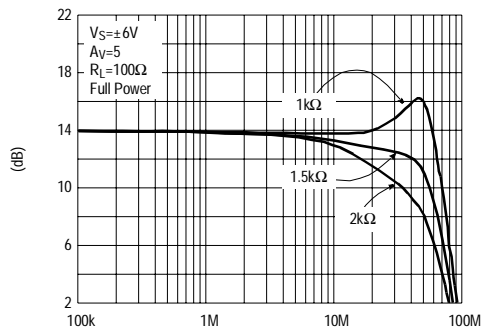
Differential Frequency Response vs  $R_F$



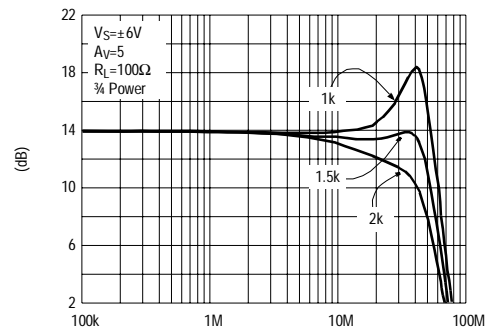
Differential Frequency Response vs  $R_F$

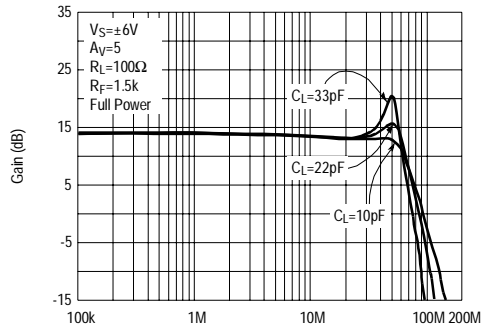
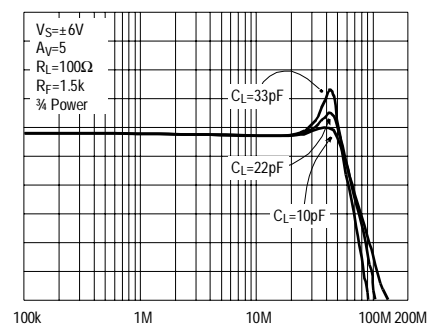
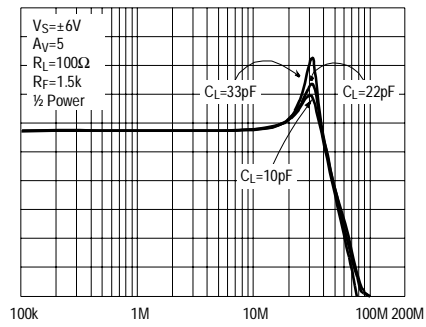


Differential Frequency Response vs  $R_F$



Differential Frequency Response vs  $R_F$



**EL1511C***Medium Power Differential Line Driver***Typical Performance Curves****Differential Frequency Response vs  $C_{LOAD}$** **Differential Frequency Response vs  $C_{LOAD}$** **Differential Frequency vs  $C_{LOAD}$** 

**EL1511C***Medium Power Differential Line Driver***General Disclaimer**

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